Single 300MHz Current Feedback Amplifier with Enable

The EL5193 and EL5193A are current feedback amplifiers with a bandwidth of 300MHz. This makes these amplifiers ideal for today's high speed video and monitor applications.

With a supply current of just 4mA and the ability to run from a single supply voltage from 5V to 10V, these amplifiers are also ideal for hand held, portable or battery-powered equipment.

The EL5193A also incorporates an enable and disable function to reduce the supply current to 100µA typical per amplifier. Allowing the $\overline{CE}$ pin to float or applying a low logic level will enable the amplifier.

The EL5193 is offered in the 5 Ld SOT-23 package and the EL5193A is available in the 6 Ld SOT-23 as well as the industry-standard 8 Ld SO packages. Both operate over the industrial temperature range of -40°C to +85°C.

Ordering Information

PART NUMBER	PART MARKING	TAPE & REEL	PACKAGE	PKG. DWG. #
EL5193CW-T7	P	7" (3K pcs)	5 Ld SOT-23	MDP0038
EL5193CW-T7A	P	7" (250 pcs)	5 Ld SOT-23	MDP0038
EL5193CWZ-T7 (Note)	BAAW	7" (3K pcs)	5 Ld SOT-23 (Pb-free)	MDP0038
EL5193CWZ-T7A (Note)	BAAW	7" (250 pcs)	5 Ld SOT-23 (Pb-free)	MDP0038
EL5193ACW-T7	P	7" (3K pcs)	6 Ld SOT-23	MDP0038
EL5193ACWZ-T7 (Note)	BAAV	7" (3K pcs)	6 Ld SOT-23 (Pb-free)	MDP0038
EL5193ACS	5193ACS	-	8 Ld SO	MDP0027
EL5193ACS-T7	5193ACS	7"	8 Ld SO	MDP0027
EL5193ACS-T13	5193ACS	13"	8 Ld SO	MDP0027
EL5193ACSZ (Note)	5193ACSZ	-	8 Ld SO (Pb-free)	MDP0027
EL5193ACSZ-T7 (Note)	5193ACSZ	7"	8 Ld SO (Pb-free)	MDP0027
EL5193ACSZ-T13 (Note)	5193ACSZ	13"	8 Ld SO (Pb-free)	MDP0027

NOTE: Intersil Pb-free plus anneal products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate termination finish, which are RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

Features

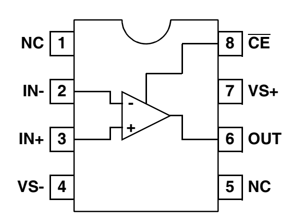
- 300MHz -3dB bandwidth
- 4mA supply current
- Single and dual supply operation, from 5V to 10V supply span
- Fast enable/disable (EL5193A only)
- Available in SOT-23 packages
- Dual (EL5293) and triple (EL5393) available
- High speed, 1GHz product available (EL5193)
- High speed, 6mA, 600MHz product available (EL5192, EL5292, and EL5392)
- Pb-free plus anneal available (RoHS compliant)

Applications

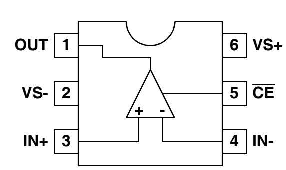
- Battery powered equipment
- Hand held, portable devices
- Video amplifiers
- Cable drivers
- RGB amplifiers
- Test equipment
- Instrumentation
- Current to voltage converters

Pinouts

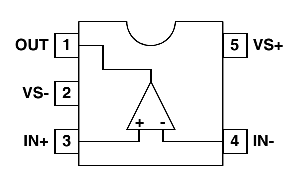
EL5193A
(8 LD SO)
TOP VIEW



EL5193A
(6 LD SOT-23)
TOP VIEW



EL5193
(5 LD SOT-23)
TOP VIEW



Absolute Maximum Ratings (T_A = 25°C)

Supply Voltage between V_S+ and V_S- 11V
Maximum Continuous Output Current 50mA
Operating Junction Temperature . . . . 125°C
Power Dissipation . . . . See Curves
Pin Voltages. . . . . V_S- -0.5V to V_S+ +0.5V
Storage Temperature. . . . . -65°C to +150°C
Ambient Operating Temperature . . . . -40°C to +85°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typical values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: $T_J = T_C = T_A$

Electrical Specifications

V_S+ = +5V, V_S- = -5V, R_F = 750Ω for A_V = 1, R_F = 400Ω for A_V = 2, R_L = 150Ω, T_A = 25°C unless otherwise specified.

PARAMETER	DESCRIPTION	CONDITIONS	MIN	TYP	MAX	UNIT
AC PERFORMANCE						
BW	-3dB Bandwidth	A_V = +1		300		MHz
		A_V = +2		200		MHz
BW1	0.1dB Bandwidth			20		MHz
SR	Slew Rate	V_O = -2.5V to +2.5V, A_V = +2	2300	2600		V/µs
t_S	0.1% Settling Time	V_{OUT} = -2.5V to +2.5V, A_V = -1		12		ns
e_N	Input Voltage Noise			4.4		nV/√Hz
i_N-	IN- Input Current Noise			17		pA/√Hz
i_N+	IN+ Input Current Noise			50		pA/√Hz
dG	Differential Gain Error (Note 1)	A_V = +2		0.03		%
dP	Differential Phase Error (Note 1)	A_V = +2		0.04		°
DC PERFORMANCE						
V_{OS}	Offset Voltage		-10	1	10	mV
T_CV_{OS}	Input Offset Voltage Temperature Coefficient	Measured from T_{MIN} to T_{MAX}		5		µV/°C
R_{OL}	Transimpedance		300	500		kΩ
INPUT CHARACTERISTICS						
CMIR	Common Mode Input Range		±3	±3.3		V
CMRR	Common Mode Rejection Ratio		42	50		dB
-ICMR	- Input Current Common Mode Rejection		-6		6	µA/V
$+I_{IN}$	+ Input Current		-60	1	80	µA
$-I_{IN}$	- Input Current		-30	1	30	µA
R_{IN}	Input Resistance			45		kΩ
C_{IN}	Input Capacitance			0.5		pF
OUTPUT CHARACTERISTICS						
V_O	Output Voltage Swing	R_L = 150Ω to GND	±3.4	±3.7		V
		R_L = 1kΩ to GND	±3.8	±4.0		V
I_{OUT}	Output Current	R_L = 10Ω to GND	95	120		mA
SUPPLY						
I_{SON}	Supply Current - Enabled	No load, V_{IN} = 0V	3	4	5	mA
I_{SOFF}	Supply Current - Disabled	No load, V_{IN} = 0V		100	150	µA

Electrical Specifications $V_S+ = +5V$, $V_S- = -5V$, $R_F = 750\Omega$ for $A_V = 1$, $R_F = 400\Omega$ for $A_V = 2$, $R_L = 150\Omega$, $T_A = 25°C$ unless otherwise specified. **(Continued)**

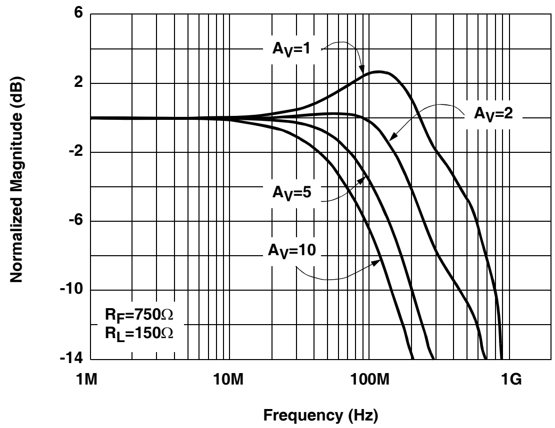
PARAMETER	DESCRIPTION	CONDITIONS	MIN	TYP	MAX	UNIT
PSRR	Power Supply Rejection Ratio	DC, V_S = ±4.75V to ±5.25V	55	75		dB
-IPSR	- Input Current Power Supply Rejection	DC, V_S = ±4.75V to ±5.25V	-2		2	µA/V
ENABLE (EL5193A ONLY)						
t_{EN}	Enable Time			40		ns
t_{DIS}	Disable Time			600		ns
I_{IHCE}	CE Pin Input High Current	$\overline{CE} = V_S+$		0.8	6	µA
I_{ILCE}	CE Pin Input Low Current	$\overline{CE} = V_S-$		0	-0.1	µA
V_{IHCE}	CE Input High Voltage for Power-down		V_S+ -1			V
V_{ILCE}	CE Input Low Voltage for Power-down				V_S+ -3	V

NOTE:

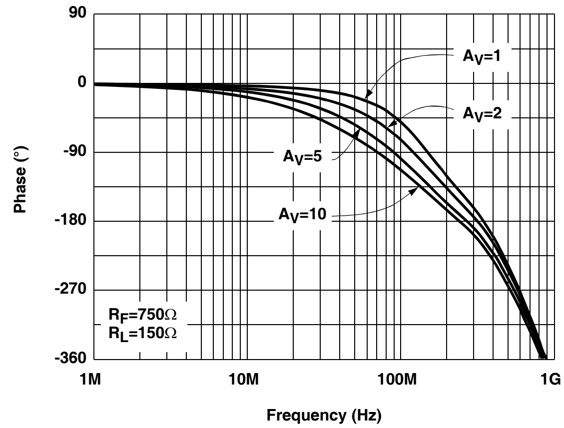
1. Standard NTSC test, AC signal amplitude = $286mV_{P-P}$, f = 3.58MHz

Typical Performance Curves

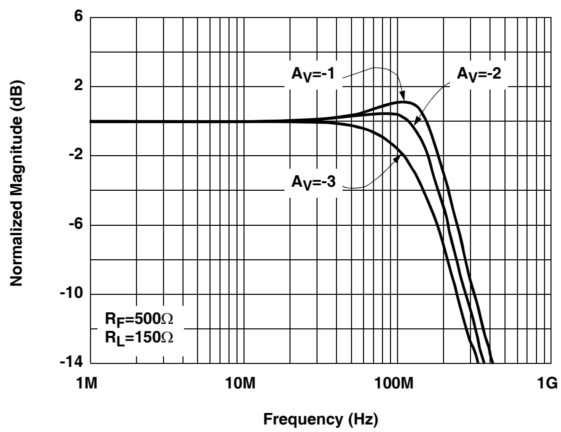
Non-Inverting Frequency Response (Gain)
SOT-23 Package



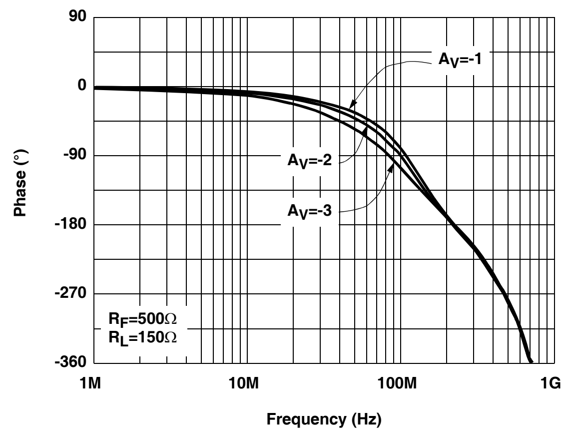
Non-Inverting Frequency Response (Phase)
SOT-23 Package



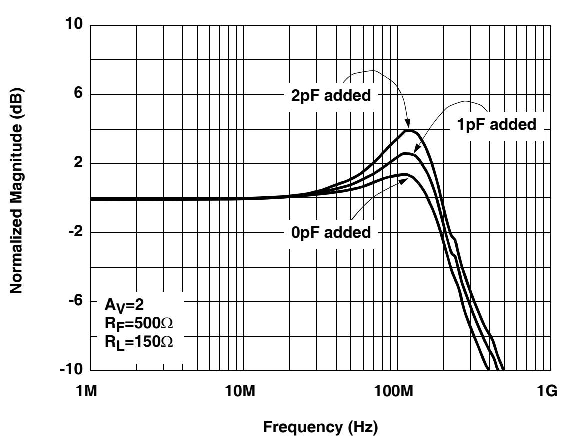
Inverting Frequency Response (Gain)
SOT-23 Package



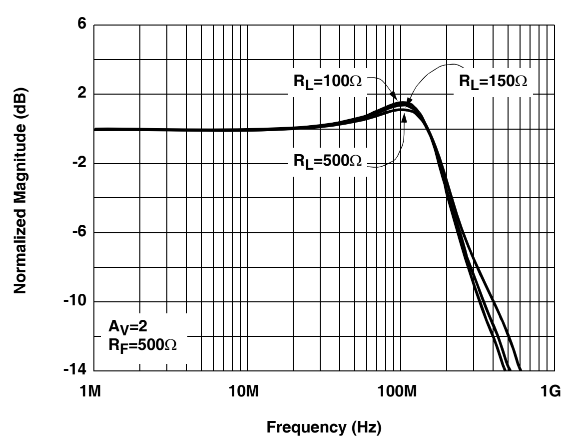
Inverting Frequency Response (Phase)



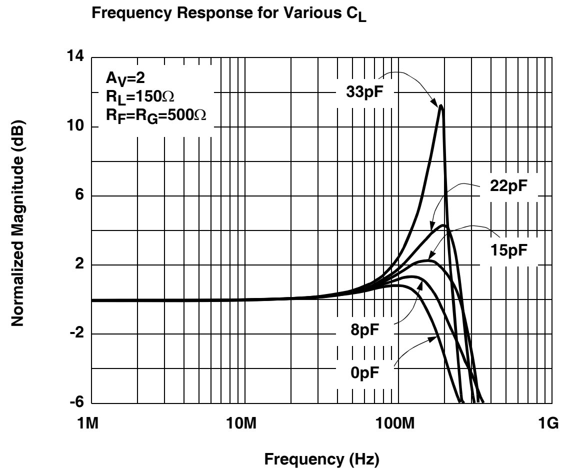
Frequency Response for Various C_{IN}-

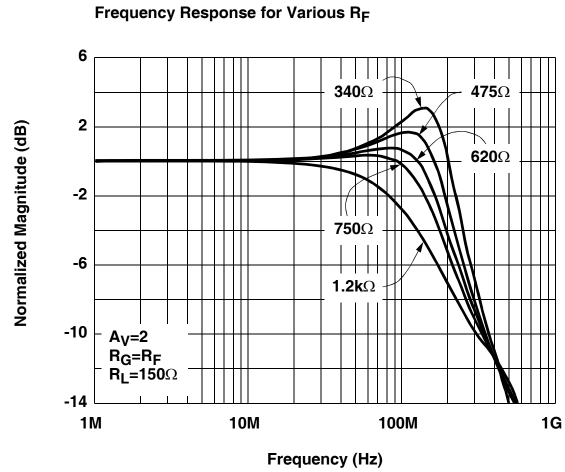


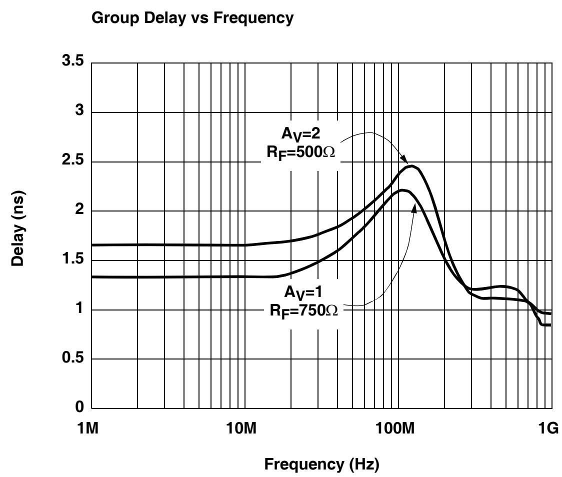
Frequency Response for Various R_L

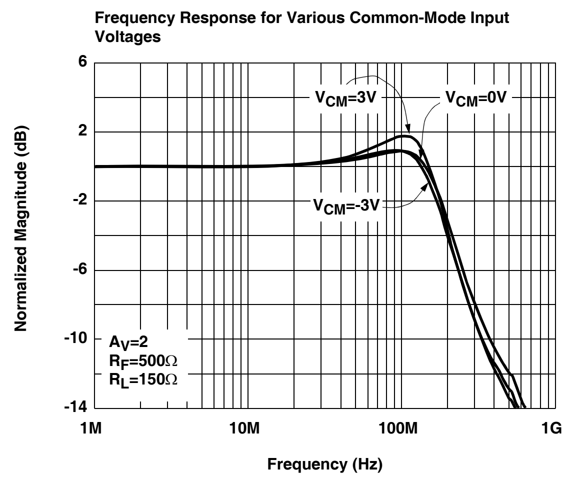


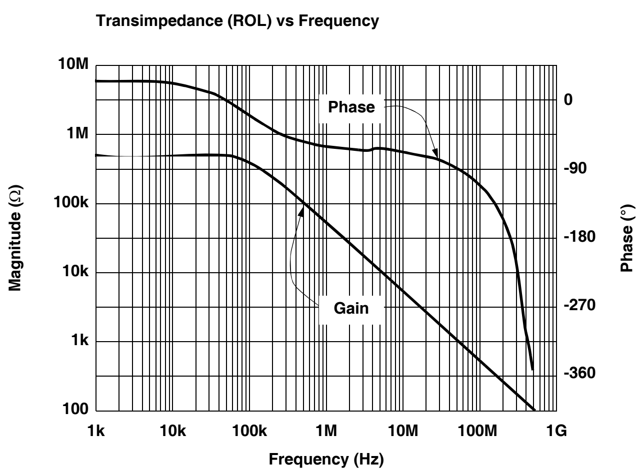
Typical Performance Curves (Continued)

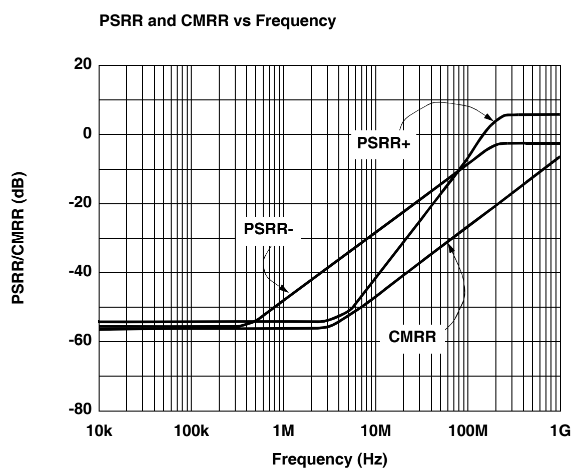




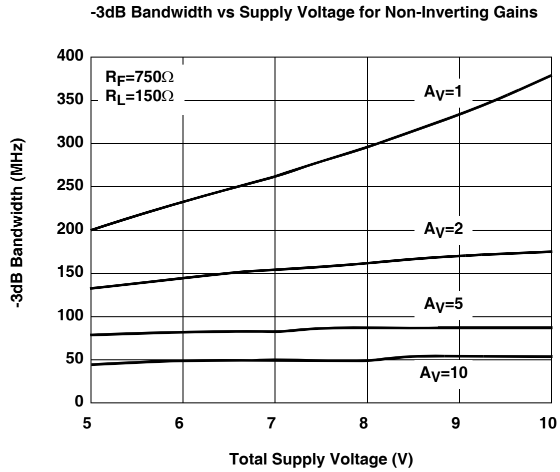


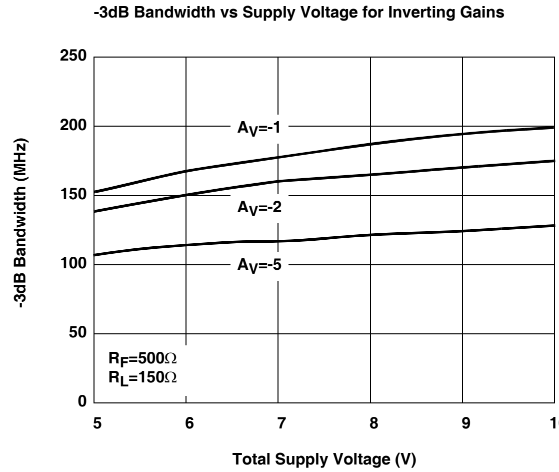


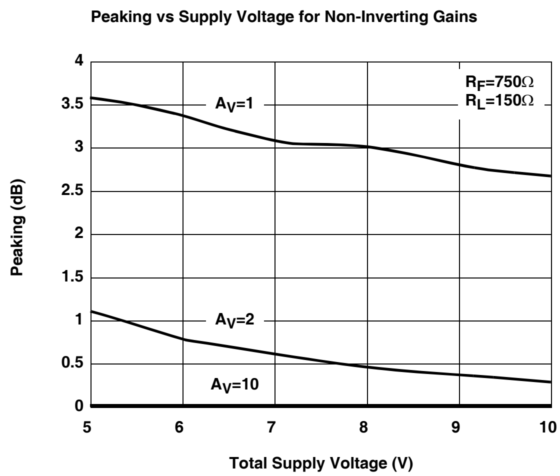


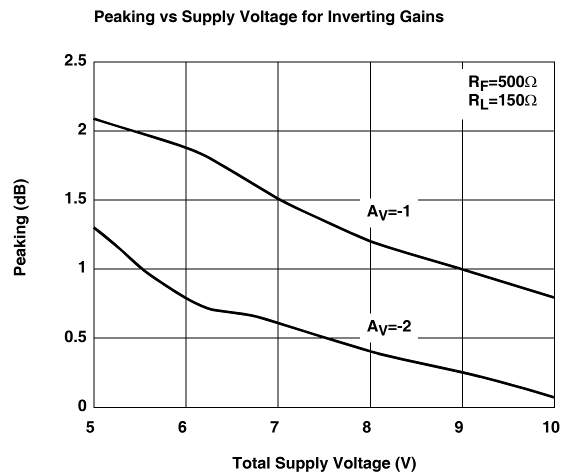


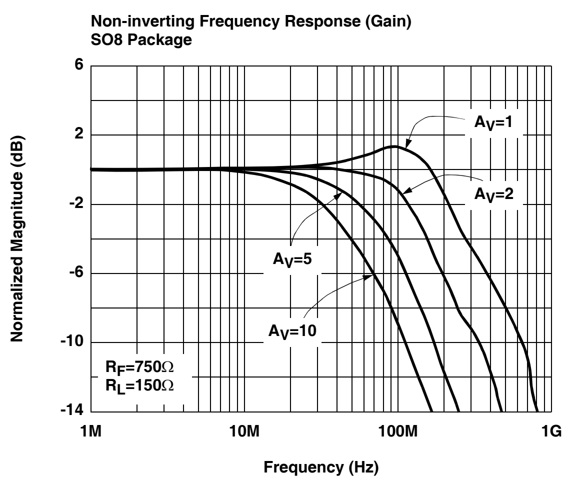
Typical Performance Curves (Continued)

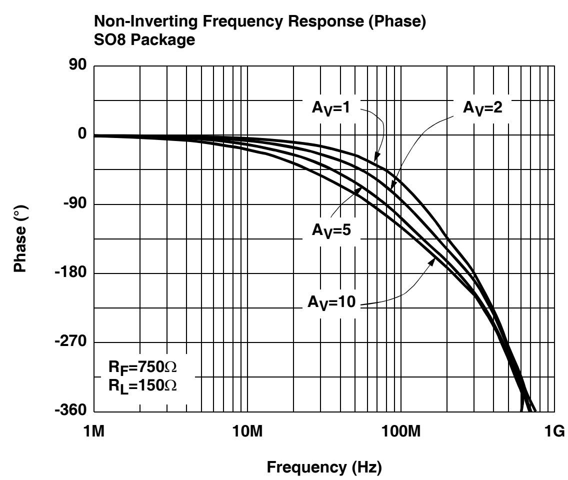






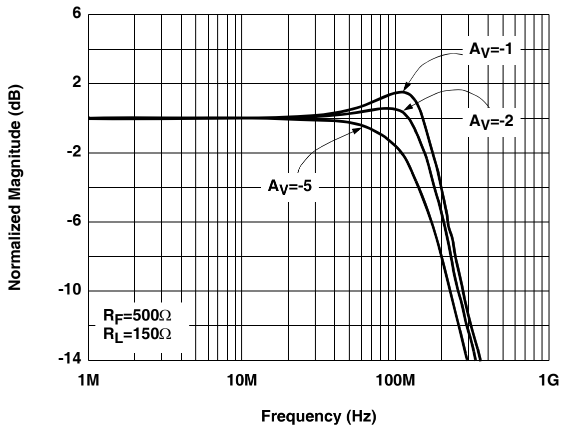




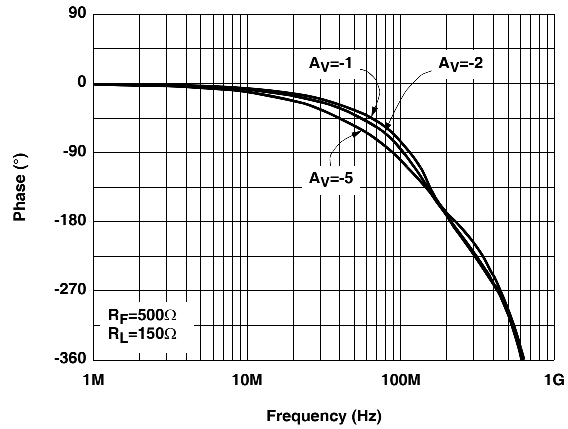


Typical Performance Curves (Continued)

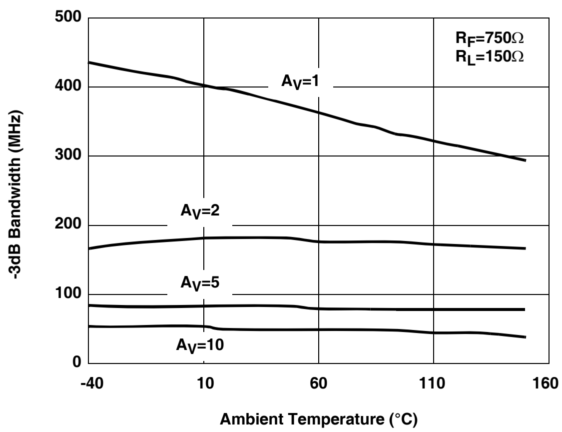
Inverting Frequency Response (Gain)
SO8 Package



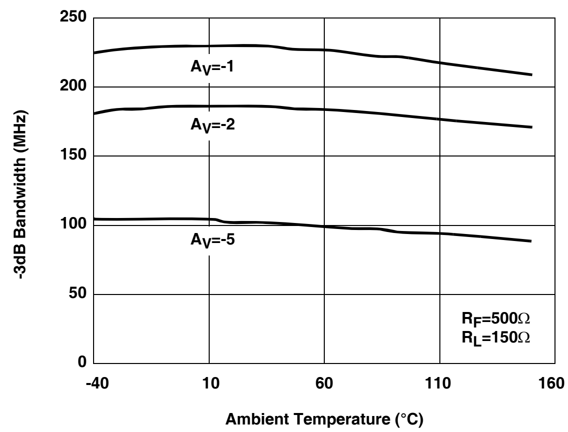
Inverting Frequency Response (Phase)
SO8 Package



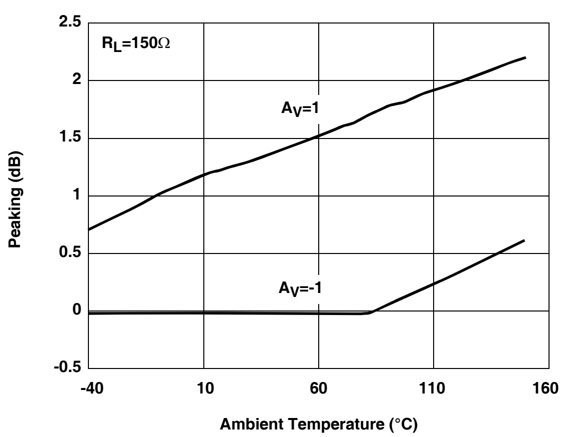
-3dB Bandwidth vs Temperature for Non-Inverting Gains



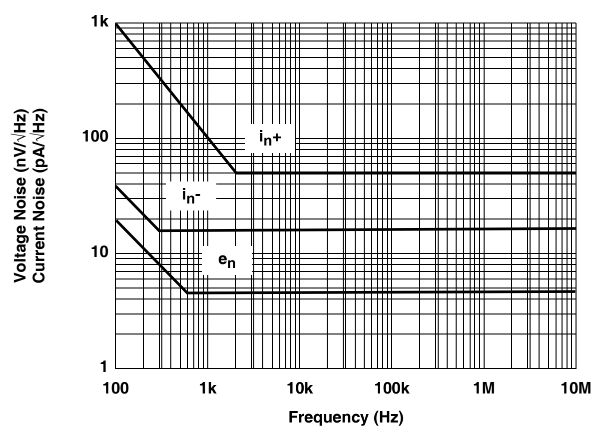
-3dB Bandwidth vs Temperature for Inverting Gains



Peaking vs Temperature

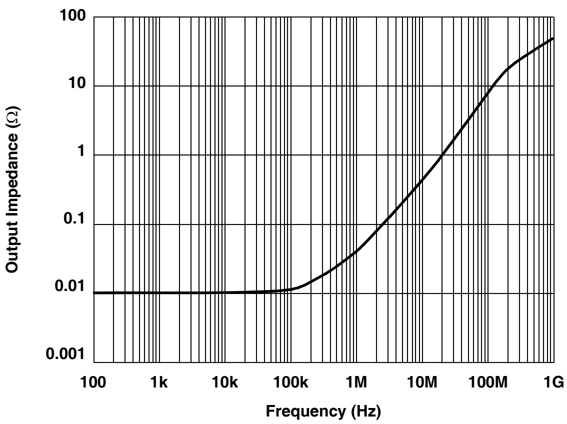


Voltage and Current Noise vs Frequency

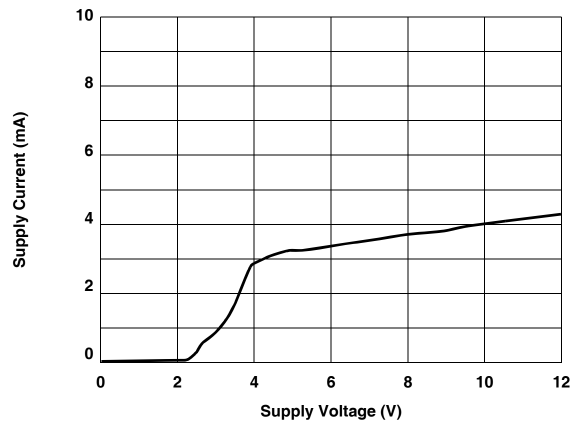


Typical Performance Curves (Continued)

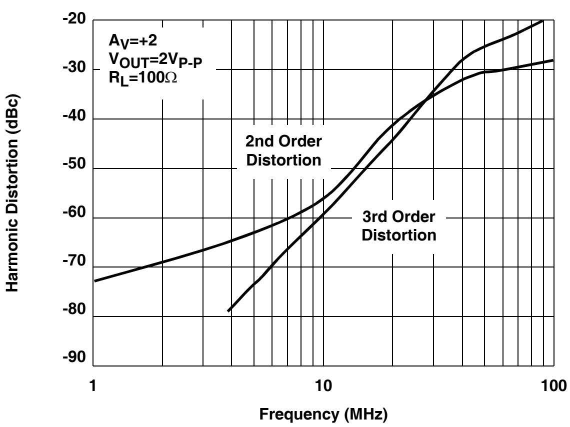
Closed Loop Output Impedance vs Frequency



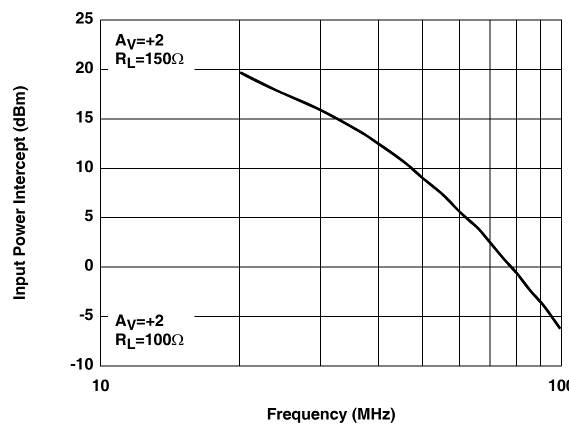
Supply Current vs Supply Voltage



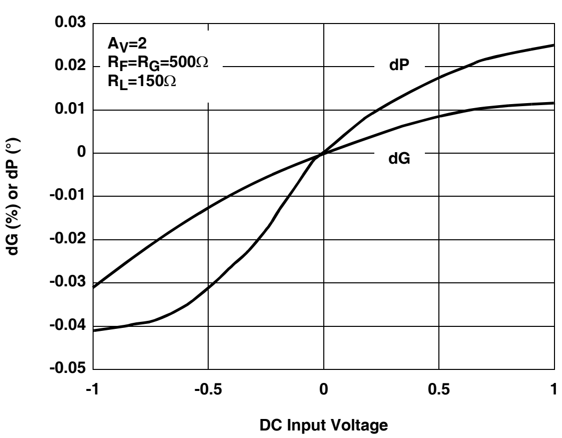
2nd and 3rd Harmonic Distortion vs Frequency



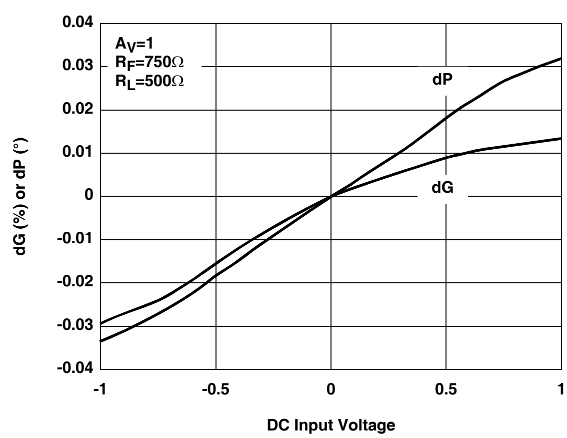
Two-Tone 3rd Order Input Referred Intermodulation Intercept (IIP3)



Differential Gain/Phase vs DC Input Voltage at 3.58MHz

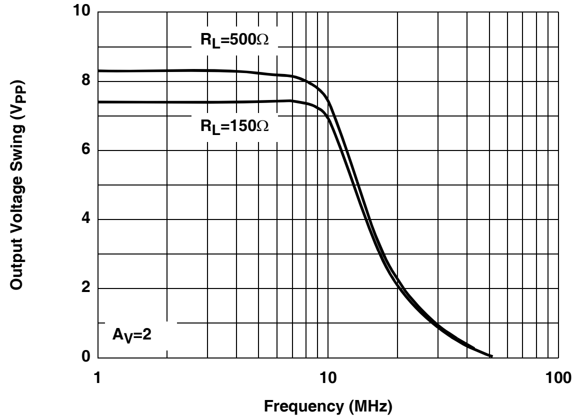


Differential Gain/Phase vs DC Input Voltage at 3.58MHz

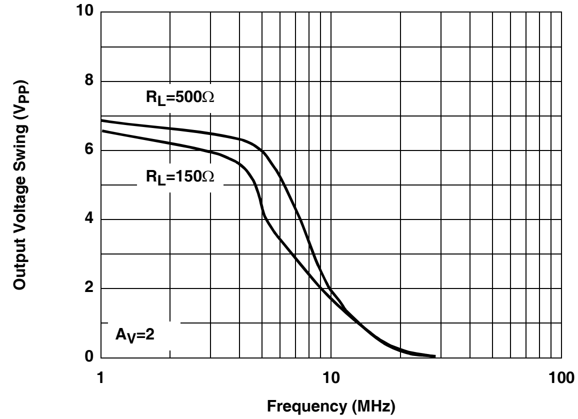


Typical Performance Curves (Continued)

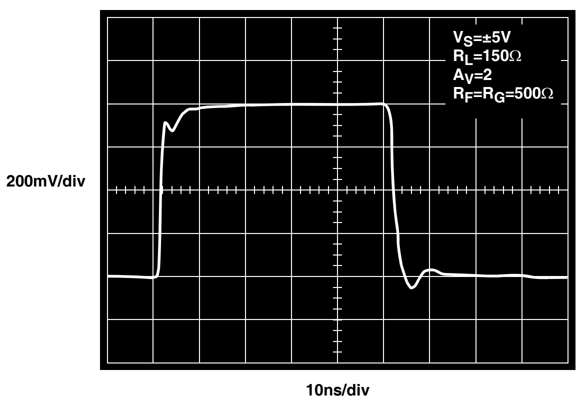
Output Voltage Swing vs Frequency THD<1%



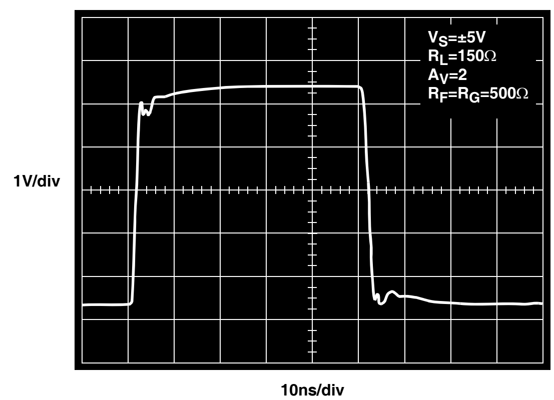
Output Voltage Swing vs Frequency THD<0.1%



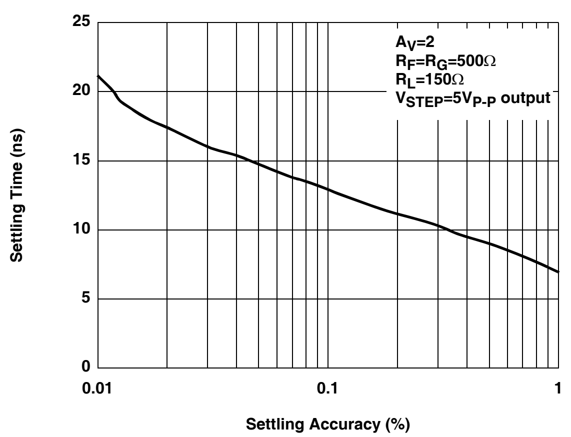
Small Signal Step Response



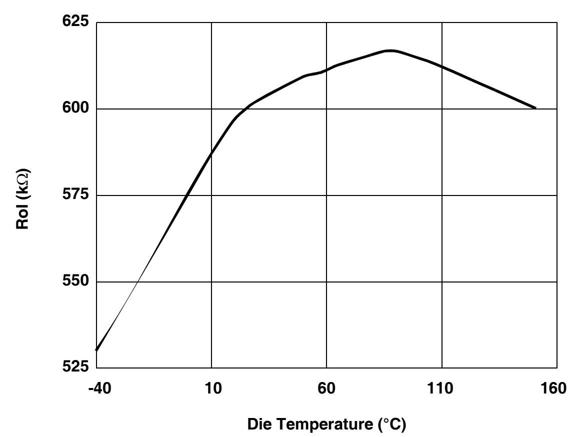
Large Signal Step Response



Settling Time vs Settling Accuracy

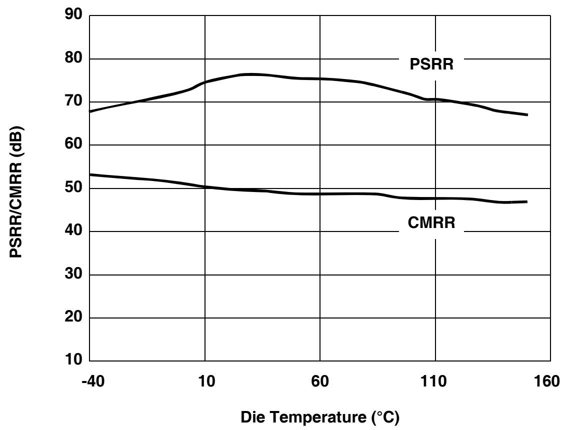


Transimpedance (RoI) vs Temperature

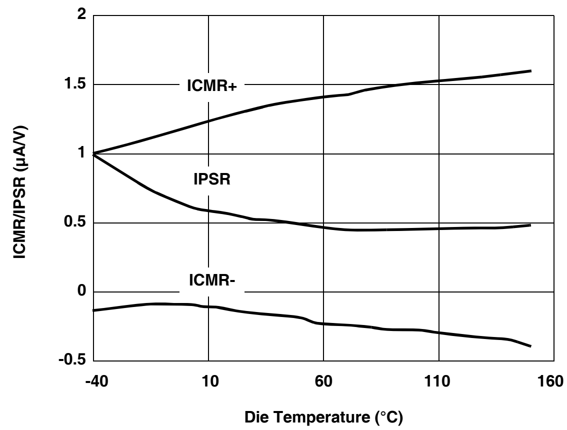


Typical Performance Curves (Continued)

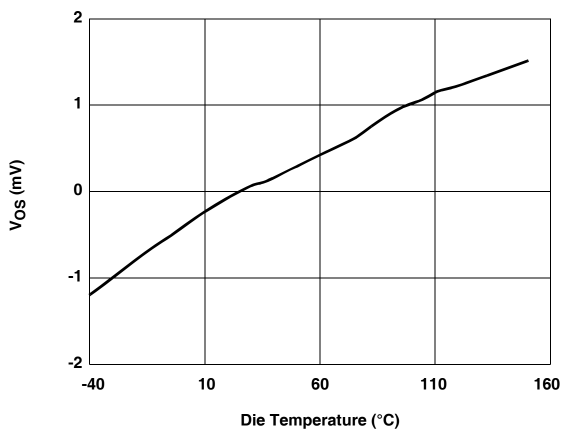
PSRR and CMRR vs Temperature



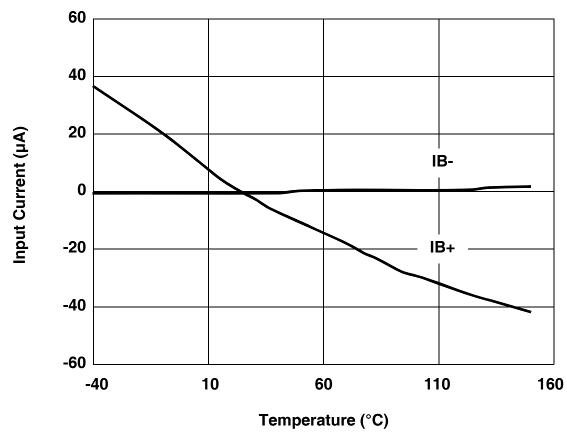
ICMR and IPSR vs Temperature



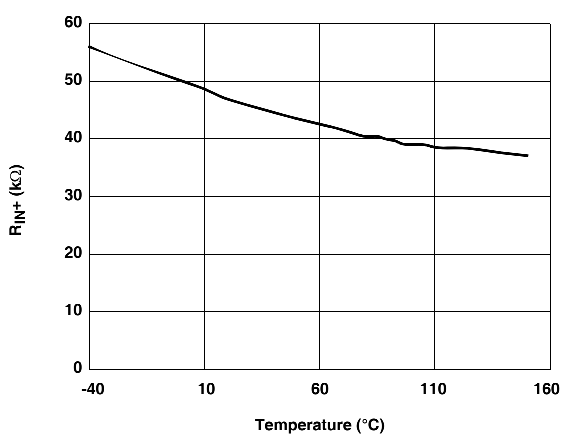
Offset Voltage vs Temperature



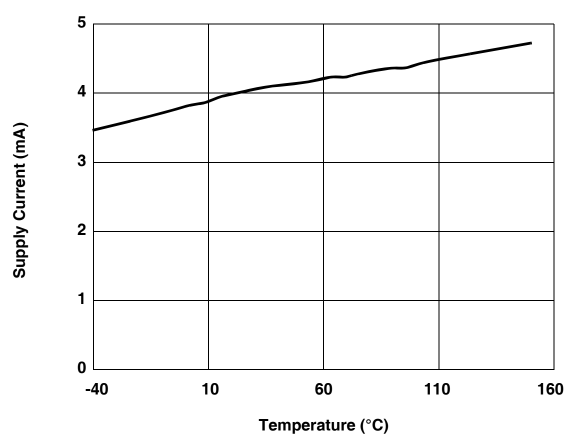
Input Current vs Temperature



Positive Input Resistance vs Temperature

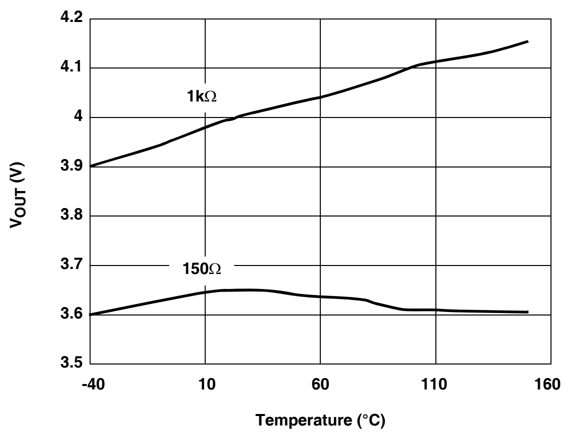


Supply Current vs Temperature

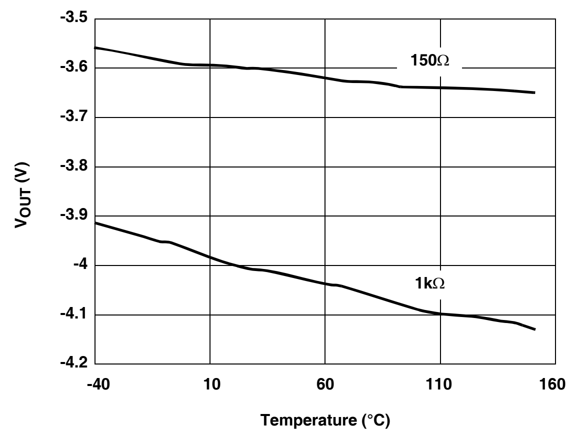


Typical Performance Curves (Continued)

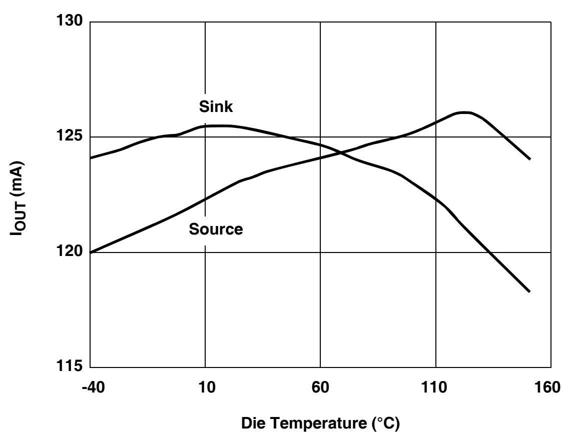
Positive Output Swing vs Temperature for Various Loads



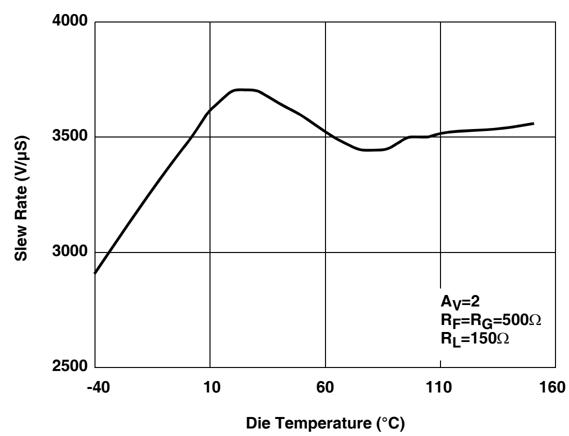
Negative Output Swing vs Temperature for Various Loads



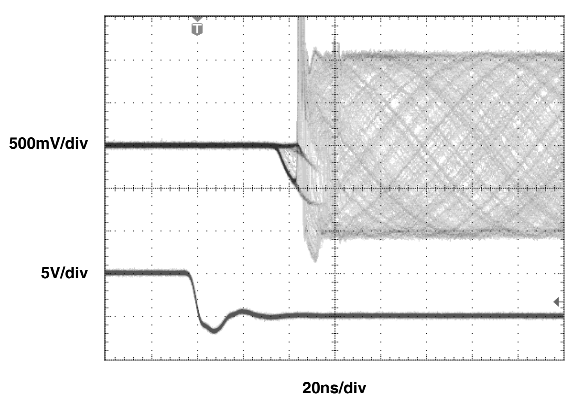
Output Current vs Temperature



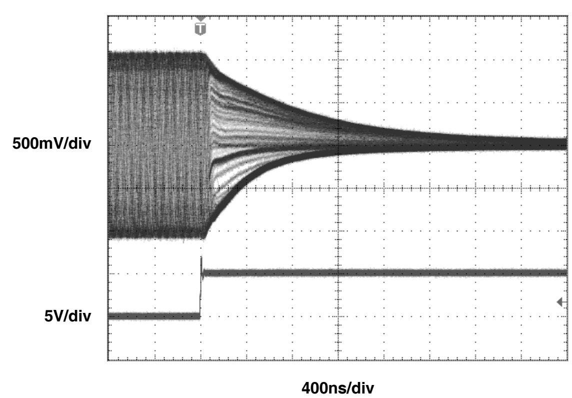
Slew Rate vs Temperature



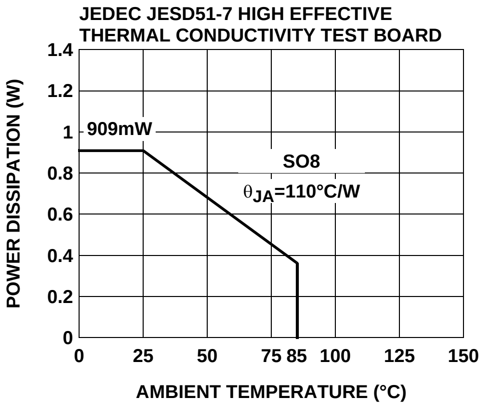
Enable Response

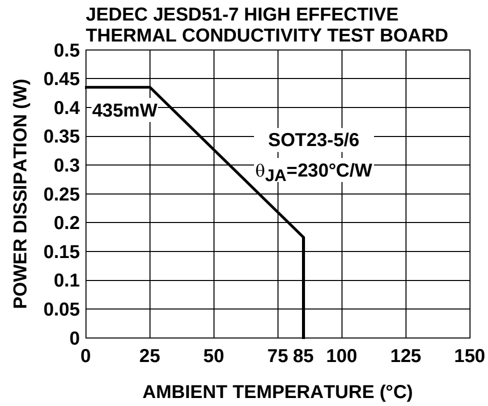


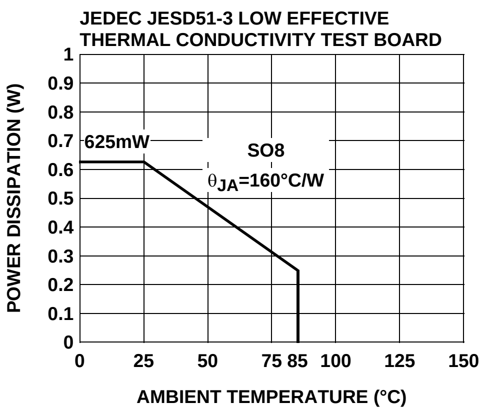
Disable Response

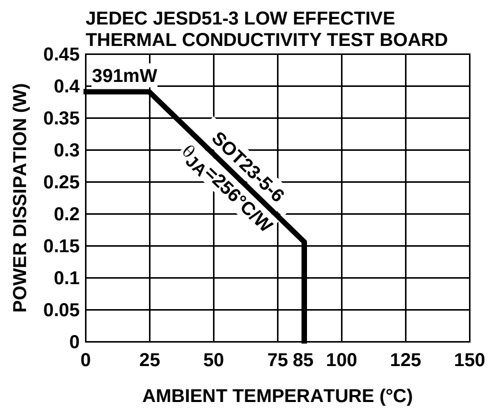


Typical Performance Curves (Continued)

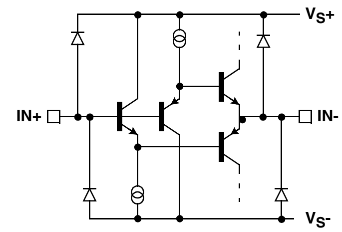
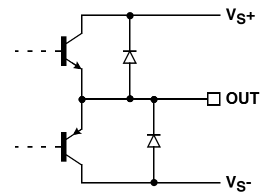
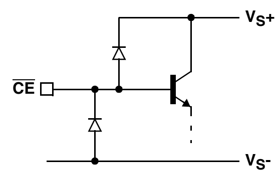








Pin Descriptions

8 LD SO	5 LD SOT-23	6 LD SOT-23	PIN NAME	FUNCTION	EQUIVALENT CIRCUIT
1, 5			NC	Not connected	
2	4	4	IN-	Inverting input	 **Circuit 1**
3	3	3	IN+	Non-inverting input	(See circuit 1)
4	2	2	V_S-	Negative supply	
6	1	1	OUT	Output	 **Circuit 2**
7	5	6	V_S+	Positive supply	
8		5	$\overline{CE}$	Chip enable	 **Circuit 3**

Applications Information

Product Description

The EL5193 is a current-feedback operational amplifier that offers a wide -3dB bandwidth of 300MHz and a low supply current of 4mA per amplifier. The EL5193 works with supply voltages ranging from a single 5V to 10V and they are also capable of swinging to within 1V of either supply on the output. Because of their current-feedback topology, the EL5193 does not have the normal gain-bandwidth product associated with voltage-feedback operational amplifiers. Instead, its -3dB bandwidth to remain relatively constant as closed-loop gain is increased. This combination of high bandwidth and low power, together with aggressive pricing make the EL5193 the ideal choice for many low-power/high-bandwidth applications such as portable, handheld, or battery-powered equipment.

For varying bandwidth needs, consider the EL5191 with 1GHz on a 9mA supply current or the EL5192 with 600MHz on a 6mA supply current. Versions include single, dual, and triple amp packages with 5 Ld SOT-23, 16 Ld QSOP, and 8 Ld or 16 Ld SO outlines.

Power Supply Bypassing and Printed Circuit Board Layout

As with any high frequency device, good printed circuit board layout is necessary for optimum performance. Low impedance ground plane construction is essential. Surface mount components are recommended, but if leaded components are used, lead lengths should be as short as possible. The power supply pins must be well bypassed to reduce the risk of oscillation. The combination of a 4.7µF tantalum capacitor in parallel with a 0.01µF capacitor has been shown to work well when placed at each supply pin.

For good AC performance, parasitic capacitance should be kept to a minimum, especially at the inverting input. (See the Capacitance at the Inverting Input section) Even when ground plane construction is used, it should be removed from the area near the inverting input to minimize any stray capacitance at that node. Carbon or Metal-Film resistors are acceptable with the Metal-Film resistors giving slightly less peaking and bandwidth because of additional series inductance. Use of sockets, particularly for the SO package, should be avoided if possible. Sockets add parasitic inductance and capacitance which will result in additional peaking and overshoot.

Disable/Power-Down

The EL5193A amplifier can be disabled placing its output in a high impedance state. When disabled, the amplifier supply current is reduced to < 150µA. The EL5193A is disabled when its $\overline{CE}$ pin is pulled up to within 1V of the positive supply. Similarly, the amplifier is enabled by floating or pulling its $\overline{CE}$ pin to at least 3V below the positive supply. For ±5V supply, this means that an EL5193A amplifier will be enabled when $\overline{CE}$ is 2V or less, and disabled when $\overline{CE}$ is above 4V. Although the logic levels are not standard TTL, this choice of logic voltages allows the EL5193A to be enabled by tying $\overline{CE}$ to ground, even in 5V single supply applications. The $\overline{CE}$ pin can be driven from CMOS outputs.

Capacitance at the Inverting Input

Any manufacturer's high-speed voltage- or current-feedback amplifier can be affected by stray capacitance at the inverting input. For inverting gains, this parasitic capacitance has little effect because the inverting input is a virtual ground, but for non-inverting gains, this capacitance (in conjunction with the feedback and gain resistors) creates a pole in the feedback path of the amplifier. This pole, if low enough in frequency, has the same destabilizing effect as a zero in the forward open-loop response. The use of large-value feedback and gain resistors exacerbates the problem by further lowering the pole frequency (increasing the possibility of oscillation).

The EL5193 has been optimized with a 475Ω feedback resistor. With the high bandwidth of these amplifiers, these resistor values might cause stability problems when combined with parasitic capacitance, thus ground plane is not recommended around the inverting input pin of the amplifier.

Feedback Resistor Values

The EL5193 has been designed and specified at a gain of +2 with R_F approximately 500Ω. This value of feedback resistor gives 200MHz of -3dB bandwidth at A_V=2 with 2dB of peaking. With A_V=-2, an R_F of approximately 500Ω gives 175MHz of bandwidth with 0.2dB of peaking. Since the EL5193 is a current-feedback amplifier, it is also possible to change the value of R_F to get more bandwidth. As seen in the curve of Frequency Response for Various R_F and R_G, bandwidth and peaking can be easily modified by varying the value of the feedback resistor.

Because the EL5193 is a current-feedback amplifier, its gain-bandwidth product is not a constant for different closed-loop gains. This feature actually allows the EL5193 to maintain about the same -3dB bandwidth. As gain is increased, bandwidth decreases slightly while stability increases. Since the loop stability is improving with higher closed-loop gains, it becomes possible to reduce the value of R_F below the specified 475Ω and still retain stability, resulting in only a slight loss of bandwidth with increased closed-loop gain.

Supply Voltage Range and Single-Supply Operation

The EL5193 has been designed to operate with supply voltages having a span of greater than 5V and less than 10V. In practical terms, this means that the EL5193 will operate on dual supplies ranging from ±2.5V to ±5V. With single-supply, the EL5193 will operate from 5V to 10V.

As supply voltages continue to decrease, it becomes necessary to provide input and output voltage ranges that can get as close as possible to the supply voltages. The EL5193 has an input range which extends to within 2V of either supply. So, for example, on +5V supplies, the EL5193 has an input range which spans ±3V. The output range of the EL5193 is also quite large, extending to within 1V of the supply rail. On a ±5V supply, the output is therefore capable of swinging from -4V to +4V. Single-supply output range is larger because of the increased negative swing due to the external pull-down resistor to ground.

Video Performance

For good video performance, an amplifier is required to maintain the same output impedance and the same frequency response as DC levels are changed at the output. This is especially difficult when driving a standard video load of 150Ω, because of the change in output current with DC level. Previously, good differential gain could only be achieved by running high idle currents through the output transistors (to reduce variations in output impedance.) These currents were typically comparable to the entire 4mA supply current of each EL5193 amplifier. Special circuitry has been incorporated in the EL5193 to reduce the variation of output impedance with current output. This results in dG and dP specifications of 0.03% and 0.04°, while driving 150Ω at a gain of 2.

Video performance has also been measured with a 500Ω load at a gain of +1. Under these conditions, the EL5193 has dG and dP specifications of 0.03% and 0.04°.

Output Drive Capability

In spite of its low 4mA of supply current, the EL5193 is capable of providing a minimum of ±95mA of output current. With a minimum of ±95mA of output drive, the EL5193 is capable of driving 50Ω loads to both rails, making it an excellent choice for driving isolation transformers in telecommunications applications.

Driving Cables and Capacitive Loads

When used as a cable driver, double termination is always recommended for reflection-free performance. For those applications, the back-termination series resistor will decouple the EL5193 from the cable and allow extensive capacitive drive. However, other applications may have high capacitive loads without a back-termination resistor. In these applications, a small series resistor (usually between 5Ω and 50Ω) can be placed in series with the output to eliminate most peaking. The gain resistor (R_G) can then be chosen to make up for any gain loss which may be created by this additional resistor at the output. In many cases it is also possible to simply increase the value of the feedback resistor (R_F) to reduce the peaking.

Current Limiting

The EL5193 has no internal current-limiting circuitry. If the output is shorted, it is possible to exceed the Absolute Maximum Rating for output current or power dissipation, potentially resulting in the destruction of the device.

Power Dissipation

With the high output drive capability of the EL5193, it is possible to exceed the 125°C Absolute Maximum junction temperature under certain very high load current conditions. Generally speaking when R_L falls below about 25Ω, it is important to calculate the maximum junction temperature (T_{JMAX}) for the application to determine if power supply voltages, load conditions, or package type need to be modified for the EL5193 to remain in the safe operating area. These parameters are calculated as follows:

$$T_{JMAX} = T_{MAX} + (\theta_{JA} \times n \times PD_{MAX})$$

where:

T_{MAX} = Maximum ambient temperature

θ_{JA} = Thermal resistance of the package

n = Number of amplifiers in the package

PD_{MAX} = Maximum power dissipation of each amplifier in the package

PD_{MAX} for each amplifier can be calculated as follows:

$$PD_{MAX} = (2 \times V_S \times I_{SMAX}) + \left[(V_S - V_{OUTMAX}) \times \frac{V_{OUTMAX}}{R_L}\right]$$

where:

V_S = Supply voltage

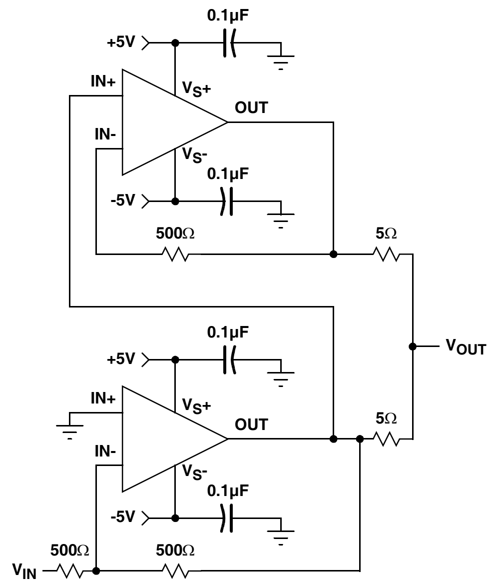
I_{SMAX} = Maximum supply current of 1A

V_{OUTMAX} = Maximum output voltage (required)

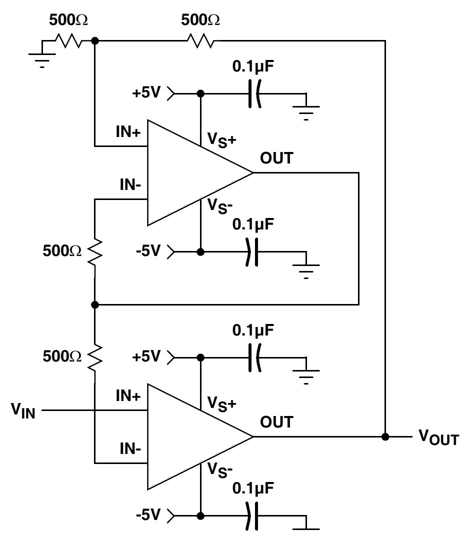
R_L = Load resistance

Typical Application Circuits

Inverting 200mA Output Current Distribution Amplifier

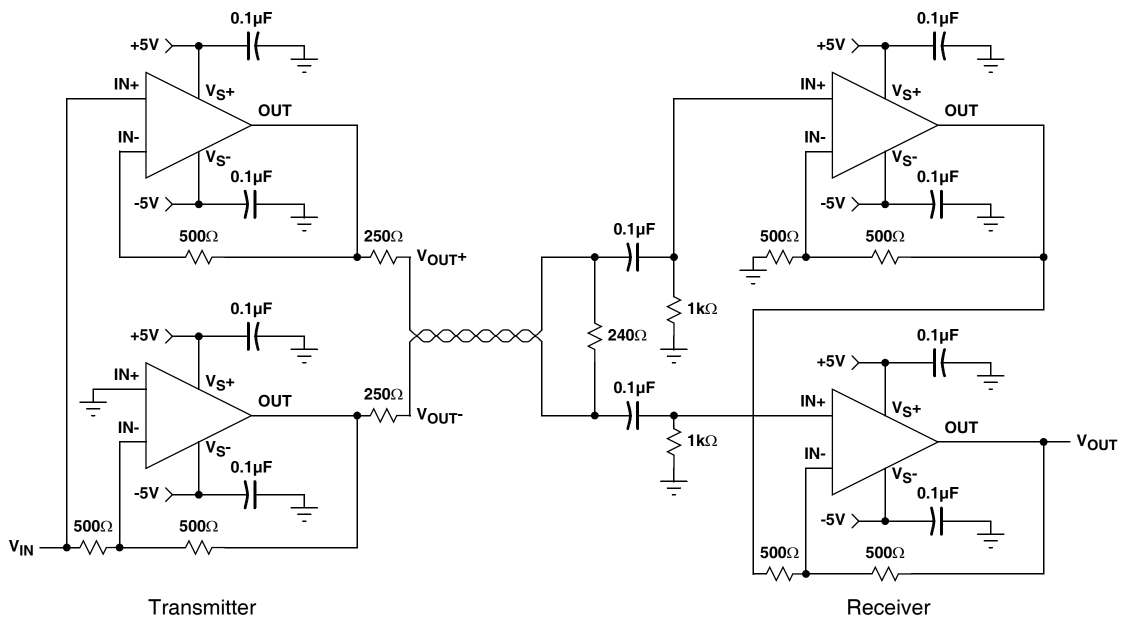


Fast-Settling Precision Amplifier

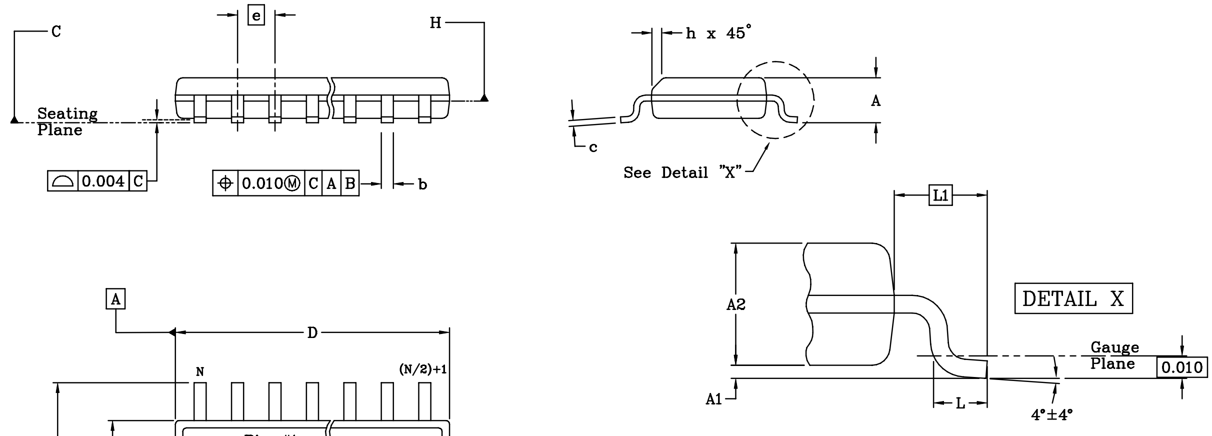


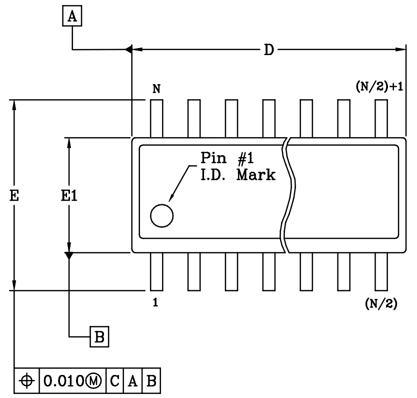
Typical Application Circuits

Differential Line Driver/Receiver



SO Package Outline Drawing





DIMENSION TABLE								
Symbol	SO-8	SO-14	SO16 (0.150")	SO16 (0.300") (SOL-16)	SO20 (SOL-20)	SO24 (SOL-24)	SO28 (SOL-28)	Tolerance
A	0.068	0.068	0.068	0.104	0.104	0.104	0.104	MAX.
A1	0.006	0.006	0.006	0.007	0.007	0.007	0.007	+/- 0.003
A2	0.057	0.057	0.057	0.092	0.092	0.092	0.092	+/- 0.002
b	0.017	0.017	0.017	0.017	0.017	0.017	0.017	+/- 0.003
c	0.009	0.009	0.009	0.011	0.011	0.011	0.011	+/- 0.001
D (1)(3)	0.193	0.341	0.390	0.406	0.504	0.606	0.704	+/- 0.004
E	0.236	0.236	0.236	0.406	0.406	0.406	0.406	+/- 0.008
E1 (2)(3)	0.154	0.154	0.154	0.295	0.295	0.295	0.295	+/- 0.004
e	0.050	0.050	0.050	0.050	0.050	0.050	0.050	Basic
L	0.025	0.025	0.025	0.030	0.030	0.030	0.030	+/- 0.009
L1	0.041	0.041	0.041	0.056	0.056	0.056	0.056	Basic
h	0.013	0.013	0.013	0.020	0.020	0.020	0.020	Reference
N	8	14	16	16	20	24	28	Reference

Drawing #: MDP0027
Rev: L
Date: 2/15/01
Units: Inches
JEDEC Reg: MS-012/013

PACKAGE OUTLINE DRAWING
SMALL OUTLINE (SO) PACKAGE FAMILY

élantec Semiconductor, Inc.
HIGH PERFORMANCE ANALOG INTEGRATED CIRCUITS

Notes:

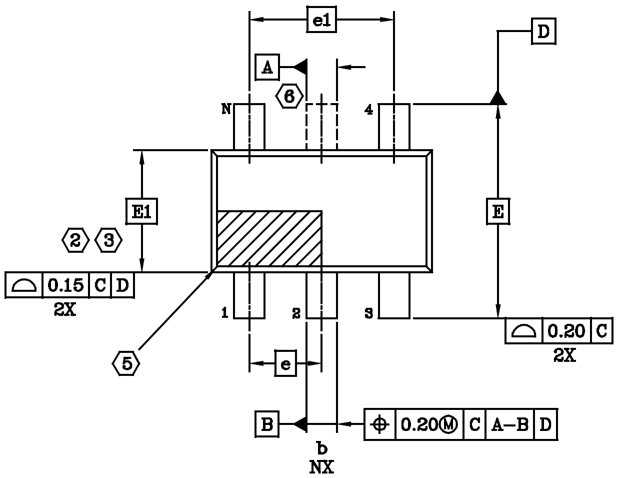
(1) Plastic or metal protrusions of 0.006" maximum per side are not included.

(2) Plastic interlead protrusions of 0.010" maximum per side are not included.

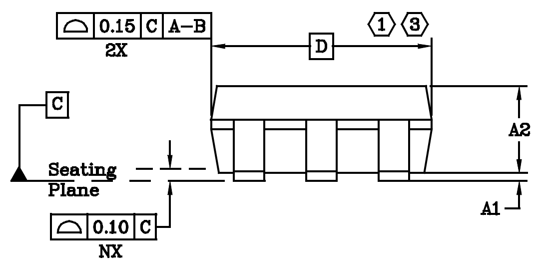
(3) Dimensions "D" and "E1" are measured at Datum Plane "H".

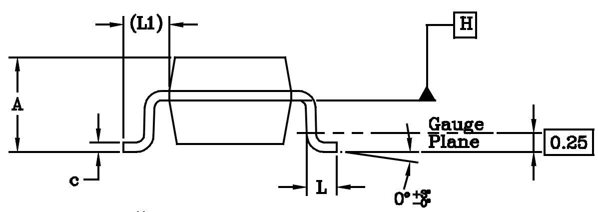
(4) Dimensioning and tolerancing per ASME Y14.5M-1994.

SOT-23 Package Outline Drawing



DIMENSION TABLE			
Symbol	SOT23-5	SOT23-6	Tolerance
A	1.45	1.45	MAX.
A1	0.10	0.10	+/- 0.05
A2	1.14	1.14	+/- 0.15
b	0.40	0.40	+/- 0.05
c	0.14	0.14	+/- 0.06
D	2.90	2.90	Basic
E	2.80	2.80	Basic
E1	1.60	1.60	Basic
e	0.95	0.95	Basic
e1	1.90	1.90	Basic
L	0.45	0.45	+/- 0.10
L1	0.60	0.60	Reference
N	5	6	Reference





Drawing #: MDP0038	PACKAGE OUTLINE DRAWING SOT-23 PACKAGE FAMILY
Rev: E	
Date: 3/13/00	
Units: mm	élantec Semiconductor, Inc. HIGH PERFORMANCE ANALOG INTEGRATED CIRCUITS
JEDEC Reg: MO-178	

Notes:

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.
3. This dimension is measured at Datum Plane "H".
4. Dimensioning and tolerancing per ASME Y14.5M-1994.
5. Index area - Pin #1 I.D. will be located within the indicated zone (SOT23-6 only).
6. SOT23-5 version has no center lead (shown as a dashed line).

NOTE: The package drawing shown here may not be the latest version. To check the latest revision, please refer to the Intersil website at http://www.intersil.com/design/packages/index.asp